Feedback e ects on the current correlations in Y-shaped conductors

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We study current uctuations in a Y-shaped conductor connected to external leads with nite impedances. We show that, due to voltage uctuations in the circuit, the moments of the transferred charges cannot be obtained from simple rescaling of the bare values already in the second moments. The cross-correlation between the output term inals can change from negative to positive under certain parameter regimes.

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Current uctuations in mesoscopic systems are of intense interest recently. Besides the fact that they inevitable exist and become more important in electric circuits when these are miniaturized, it is now wellappreciated that they contain interesting and fundam entalphysics (see, e.g., [1, 2, 3]). For example, Ferm istatistics of the electrons are responsible for the reduction of the shot noise as compared with a corresponding system of classical or Bosonic particles. Furtherm ore, the sam e Ferm i statistics of the charge carriers have in portant implications in multi-term inal setups. The quantity of interest in this case is the cross-correlation between di erent term inals [1, 4, 5, 6]. Experim ent of this type is the solid-state analogue of the Hanbury Brown-Twiss experiment in quantum optics [7]. It has been shown that generally Ferm i statistics in plies that the cross-correlations between the currents in two di erent output arm s are negative [4, 5, 6]. This theoretical result assumes non-interacting electrons and is supported by experiments available so far [8].

The sign of this cross-correlation has triggered m any investigations into the question as to under what circum – stances it would be reversed. Several m echanisms have been proposed. A few invoke possible electronic ground states that are not norm alm etallic (Landau-Ferm i liquid) states, such as superconducting (e.g. [9]), quantum H all, or Luttinger liquids states (e.g. [10]). Still another m echanism has been proposed relying on nite frequency and capacitive couplings [11], and one in ferrom agnetic system sbased on \bunching" of transferred electrons due to spin blockade [12].

Here we show that a feedback mechanism in the presence of external in pedances can also lead to this sign change. We consider the system as shown in Fig.1. The \sam ple" A is a Y-shaped conductor in which electrons propagate coherently. It can consist of tunnel barriers or di usive conductors, and is connected to external resistors Z_a , Z_b and Z_c . Our considerations are also of relevance for practical measurements (c.f. [13]). In measurements of cross-correlations, one injects an incident beam of charge carriers (here from reservoir a) and then splits the beam into two parts using a \beam splitter", such as the Y-shaped conductor here. One would like to measure the current correlation between two output term inals, here b and c. In most current measurements however, one needs to couple the sam ple to external measuring circuits. For example, here we are considering the case where the current measurements are actually made by voltage measurements across the impedances Z_b and Z_c . If the external measuring circuit can be idealized as having zero impedance, then the voltage across the sam – ple would be non- uctuating and the current uctuations are entirely due to intrinsic properties of the sam ple and the carriers. With nite external impedances, the voltage across the sample then becomes uctuating and the current correlations will be modi ed.

Previously, feedback due to the presence of external im pedances has been considered for two-term inal conductors [1], and more recently, in the context of third mom ent of the shot noise [13, 14, 15, 16]. The results based on the Langevin form alism [1] concluded that the second moments of current uctuations can be obtained from the corresponding zero-impedance (intrinsic or \bare") values by a simple scaling. However, it was shown, using both a Keldysh technique [14, 15] and the Langevin formalism [15, 16], that this rescaling breaks down at the third moment. In this work we show that, for our threeterm inal setup, even the second m om ent cannot be obtained from a rescaling of the corresponding bare value. For instance, the cross-correlation acquires contributions from auto-correlators. Since the bare auto-correlators are always positive, it is then possible to have positive crosscorrelations in appropriate param eter regim es. The e ect of external in pedances on current uctuations of multiterm inal circuits has also been considered by Buttiker and his collaborators [1] using the Langevin form alism . However, they considered a multiprobe measurem ent of a two-term inal conductor and thus not directly our geom etry here.

We have performed the calculations using both the Langevin and Keldysh formalisms [17]. The results are identical. To illustrate the physics more clearly, let us rst consider a simplified case where only $Z_b \in 0$ using the Langevin formalism. Let us rst introduce some

short-hand notations. We denote the conductances of the three arms of our sample as G_a , G_b , G_c . We shall de ne $G_a + G_b + G_c$ and also the dimensionless param eters $a_a - G_a = G$ etc (thus $a_a + b_b + c_c = 1$). In the present situation, the potentials a_1 and a_3 at points 1 and 3 are given by the external potentials V_a and V_c respectively and do not uctuate. How ever, the quantity a_2 is a uctuating quantity. The current in an arm b, say, is a linear combination of two contributions, one being linear in the bias potentials 's and another due to the Langevin noise. Thus we have

$$I_b = G_b [a(V_2) c_2] + I_2$$
: (1)

The rst term follows easily from circuit theory. I_2 is the Langevin noise whose expectation value is zero. We shall specify its variance later. Similarly for arm c, we have

$$I_c = G_c [_aV + _b_2] + I_3$$
: (2)

The uctuating potential $_2$ is related to I_b by

$$_{2} = I_{b}Z_{b}$$
: (3)

(W e are interested in the zero frequency lim it so the current along arm A_b is equal to that through the resistor Z_b .) By taking the expectation values of (1)-(3), we can obtain $\overline{I_b}$, $\overline{I_c}$ and $\overline{2}$. In particular, we have

$$\frac{1}{2} = \frac{1}{\mathbb{Z}_{t}} \mathbb{Z}_{b} \mathbb{G}_{a \ b} \mathbb{V} :$$
(4)

Here z_t 1+ $Z_bG_b(_a + _c)$ is a dimensionless quantity. Subtracting the expectation values of Eqs. (1)-(3) from these equations them selves, we nd, by eliminating $_2$ $_2$ in favor of I_b $\overline{I_b}$,

$$I_{b} \qquad I_{b} \qquad \overline{I_{b}} = \frac{1}{z_{t}} \quad I_{2}; \qquad (5)$$

$$I_{c} \qquad I_{c} \qquad \overline{I_{c}} = \frac{1}{z_{t}} Z_{b} G_{b c} \qquad \underline{I}_{c} + \underline{I}_{c} : \qquad (6)$$

From these, we can readily obtain the uctuations h I $_{\rm b}$ I $_{\rm c}i$ etc. (W e have out the frequency variables for simplicity here. See below form ore accurate notations). In particular,

$$h I_b I_c i = \frac{1}{z_t^2} Z_b G_b ch \not L J_i + \frac{1}{z_t} h \not L J_i:$$
(7)

This shows immediately that the cross-correlation has several contributions. Besides one which is a rescaling of the \bare" correlator h $\downarrow_{\rm L}$ i, there is another contribution being proportional to h $\downarrow_{\rm L}$ i. The origin of this latter term is obvious also from the above derivation, that is, the sam ple is \driven" by the potential _2 which is itself uctuating. To com plete the calculation we need the expressions for h $\downarrow_{\rm L}$ i and h $\downarrow_{\rm L}$ i. For this, we have to notice that the sam ple is now biased at voltages V at point 1, _2 at point 2, and 0 at point 3. Let us de ne the bare (superscript ⁽⁰⁾) correlators C⁽⁰⁾_{bc} by the expression h $\downarrow_{\rm L}$ (!) $\downarrow_{\rm L}$ (!) i=2 (! + !) C⁽⁰⁾_{bc} etc. In the shot noise (tem perature T ! 0) regime, we expect these correlators to be linear combinations of contributions that are proportional to the average potential di erences, i.e.,

$$C_{bb}^{(0)} = e = s_{bb}^{(b)} (V - 2) + s_{bb}^{(c)} (V - 0); \qquad (8)$$

$$C_{bc}^{(0)} = e = s_{bc}^{(b)} (V - 2) + s_{bc}^{(c)} (V - 0): \qquad (9)$$

The values of the coe cients s $_{bb}^{(b)}$ etc will be given below. Here the superscripts are denoted according to the potentials relative to a and the subscripts, the currents. W riting h I_b(!) I_c(!⁰)i = 2 (! + !⁰)C_{bc}, we can now obtain the \renorm alized" correlator C_{bc} (which is also proportional to the correlators for transferred charges) from Eq. (7), using (4), (8) and (9):

$$C_{bc} = \frac{(Z_{b}G_{bc})(1 + Z_{b}G_{bc})}{z_{t}^{3}}s_{bb}^{(b)} + \frac{(1 + Z_{b}G_{bc})}{z_{t}^{2}}s_{bc}^{(b)} + \frac{(Z_{b}G_{bc})}{z_{t}^{2}}s_{bb}^{(c)} + \frac{1}{z_{t}}s_{bc}^{(c)} + \frac{1}{z_{t}}s_{bc}^{(c)} eV :$$
(10)

The modi cations needed for our general case are straight-forward in principle. We simply state our nal results:

$$C_{bb} = \frac{eV}{z_{t}^{3}} (P + S) P^{2} s_{bb}^{(b)} + Q^{2} s_{cc}^{(b)} + 2P Q s_{bc}^{(b)} + (Q + R) P^{2} s_{bb}^{(c)} + Q^{2} s_{cc}^{(c)} + 2P Q s_{bc}^{(c)};$$
(11)

$$C_{cc} = \frac{eV}{z_{t}^{3}}^{n} (P + S)^{n} S^{2} s_{bb}^{(b)} + R^{2} s_{cc}^{(b)} + 2SR s_{bc}^{(b)}^{l} + (Q + R)^{n} S^{2} s_{bb}^{(c)} + R^{2} s_{cc}^{(c)} + 2SR s_{bc}^{(c)}^{l}; \qquad (12)$$

$$C_{bc} = \frac{eV}{z_{t}^{3}} (P + S) PS_{bb}^{(b)} + QRS_{cc}^{(b)} + (PR + QS)S_{bc}^{(b)} + (Q + R) PSS_{bb}^{(c)} + QRS_{cc}^{(c)} + (PR + QS)S_{bc}^{(c)} :(13)$$

In these equations

is a dimensionless number, and the symbols P;Q;R;S

$$z_{t} = a (1 + GZ_{b b}) (1 + GZ_{c c}) + b (1 + GZ_{c c}) (1 + GZ_{a a}) + c (1 + GZ_{a a}) (1 + GZ_{b b})$$
(14)

stand for

$$P = 1 + Z_{a}G_{a c} + Z_{c}G_{c}(a + b);$$

$$Q = Z_{a}G_{a b} + Z_{c}G_{b c};$$

$$R = 1 + Z_{a}G_{a b} + Z_{b}G_{b}(a + c);$$

$$S = Z_{a}G_{a c} + Z_{b}G_{b c}:$$
(15)

The coe cients $s_{bb}^{(b)}$ etc in Eqs. (11)-(13) are the same as those entering Eqs. (8), (9). Generalization of the intrinsic (bare") correlation between arm s and in the shot noise regime is thus (c.f. Eqs. (8), (9))

$$C^{(0)} = e = s^{(b)} (1 - 2) + s^{(c)} (1 - 3) :$$
 (16)

These coe cients take di erent form s for tunnel junctions and for di usive wires. For tunnel junctions, if $\frac{1}{2}$, they are given by

$$s_{bb}^{(b)} = G_{b}[a(1 \ 2_{ab}) \ c(1 \ 2_{bc})];$$

$$s_{bb}^{(c)} = G_{bc}(1 \ 2_{bc});$$

$$s_{cc}^{(c)} = G_{bc}(1 \ 2_{ac} \ 2_{bc});$$

$$s_{cc}^{(c)} = G_{c}[a(1 \ 2_{ac}) + b(1 \ 2_{ac} \ 2_{bc})];$$

$$s_{bc}^{(b)} = G_{bc}(1 \ 2_{a}^{2} \ 2_{ac} \ 2_{bc});$$

$$s_{bc}^{(c)} = G_{bc}(1 \ 2_{a}^{2} \ 2_{ac} \ 2_{bc});$$

$$(17)$$

In the case 1 3 2 [18], the corresponding coefcients can be obtained from the above expressions by exchanging the indices b and c. For example, $s_{cc}^{(b)}$ can be obtained from the above expression for $s_{bb}^{(c)}$ with all indices of its right hand members making the exchange b\$ c. For di usive wires, if 1 2 3,

$$s_{bb}^{(b)} = \frac{G}{3} \ _{b}(a \ _{c}); \qquad s_{bb}^{(c)} = \frac{G}{3} \ _{b} \ _{c}(1 + 2 \ _{a});$$

$$s_{cc}^{(b)} = \frac{G}{3} \ _{b} \ _{c}(2 \ _{a} \ _{1}); \qquad s_{cc}^{(c)} = \frac{G}{3} \ _{c}(a + \ _{b});$$

$$s_{bc}^{(b)} = \frac{G}{3} \ _{b} \ _{c}(1 \ _{2} \ _{a}); \qquad s_{bc}^{(c)} = \frac{G}{3} \ _{b} \ _{c}: (18)$$

Again, for 1 3 2, one can get the coe cients by exchanging b\$ c in the form ulas above. These coefcients have been calculated using generalization of the m ethods proposed by Nazarov [19]. Som e of these coefcients can also be deduced from the literature (e.g. [6], [9], and [20]).

Equations (11)–(15) are the main analytic results of this paper. The auto-correlators C_{bb} and C_{cc} can be shown to be positive de nite [17]. We shall concentrate on the cross-correlation C_{bc} for the rest of the paper.

For C_{bc} , we can show that [17] it is always negative if Z_{a} a is larger than Z_{b} b and Z_{c} . Hence, we shall focus on the rest of the parameter space. We show the results for two particular examples, $Z_{a} = 0$, $Z_{b} = Z_{c} = 1=G$ in Fig. 2, and $Z_{a} = 0$, $Z_{b} = Z_{c} = 10=G$ in Fig. 3. We see

that, for su ciently large Z $_{\rm b}$ and Z $_{\rm c}$, it is indeed possible to have positive C $_{\rm bc}$. The positive region starts near sm all $_{\rm a}$, and grows with increasing Z $_{\rm b}$ and Z $_{\rm c}$. Indeed, for Z $_{\rm b}$ and Z $_{\rm c}$ both ! 1, one can show that the cross-correlation actually becomes positive for any 's. (This sign change is not con ned to Z $_{\rm a}$ = 0, form ore examples, see [17].)

We can understand this behavior physically as follows. (Form ore quantitative statements, see [17].) When there is a positive uctuation of the current through, say the arm b, there is a corresponding increase in the potential at point 2 in Fig. 1. This voltage uctuation in turn will lead to an extra current through the arm c, thus giving a positive contribution to the cross-correlation C_{bc} . This contribution will in particular be large for small a, since m ost of this uctuating current will ow through c. We have a net positive C_{bc} if these contributions overwhelm the \bare" negative correlation contribution (see Eq. (13)). In particular, since $s_{bc}^{(b)} + s_{bc}^{(c)} (< 0)$ is proportional to $\frac{2}{a}$ for tunnel junctions whereas it is proportional to $_{a}$ for di usive wires for small $_{a}$, it is therefore easier to get positive C_{bc} for tunnel junctions than for di usive wires.

Our mechanism for sign change is distinct from that due to bunching (c.f. [12]). We have calculated also the Fano factors and found no bunching in the injected current [17].

In conclusion, we have shown that, for a multiterm inal conductor connected to external leads with nite im pedances, the m om ents of the transferred charges cannot be obtained from simple rescaling of the bare m om ents. The cross-correlation between the output term inals can even become positive under certain parameter regim es.

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FIG. 1: Schematic for the circuit considered in this paper. The arm s A_a , A_b , A_c of the Y-shaped conductor A are connected to external leads biased, respectively, at voltages $V_a = V$, V_b , and V_c ($V_b = V_c = 0$ in this paper). The leads are assumed to have in pedances Z_a , Z_b , and Z_c , which are schematized as external resistors connected to the sam – ple arm s. The nodes 1;2;3 between the sam ple arm s and the resistors are where voltage uctuations set in.

FIG. 2: Plots for the cross-correlations of Y-shaped conductors with (a) tunnel junctions and (b) di usive wires in the arm s. Here the external impedances are $Z_a = 0$ and $Z_b = Z_c = 1=G$. C_{bc} is in units of eGV and the thick lines over the surfaces m ark the contour $C_{bc} = 0$.

FIG .3: Sam e as Fig.2 except that impedances are $\rm Z_{a}$ = 0 and $\rm Z_{b}$ = $\rm Z_{c}$ = 10=G .